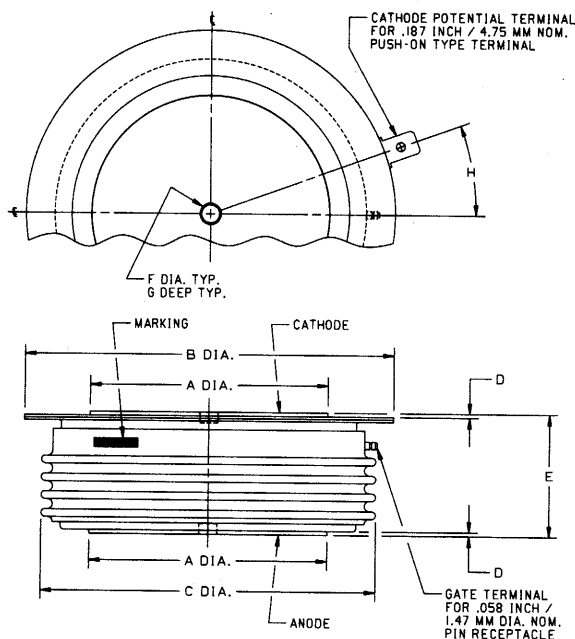


Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272
Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

Phase Control SCR
1000 Amperes Average
2400 Volts



CASE NUMBER T9G			STRIKE DISTANCE : .58 INCH / 14.7 MM MIN.					
NOMINAL DIMENSIONS			CREEPAGE DISTANCE : 1.00 INCH / 25.4 MM MIN.					
SYM.	A	B	C	D	E	F	G	H
INCHES	1.85	2.90	2.60	.030	1.000/1.090	.140	.085	20°
MM	47.0	73.7	66.0	0.76	25.40/27.69	3.56	2.16	20°

T9G0 1000A (Outline Drawing)



T9G0 1000A Phase Control SCR
1000 Amperes Average, 2400 Volts

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

Features:

- ☐ Low On-State Voltage
- ☐ High di/dt Capability
- ☐ High dv/dt Capability
- ☐ Hermetic Packaging
- ☐ Excellent Surge and I^2t Ratings

Ordering Information:

Select the complete 12 digit part number you desire from the table below.

Type	Voltage	Current	Turn-off	Gate Current	Lead Code
	V_{DRM}/V_{RRM} (Volts)	$I_{T(av)}$ (A)	t_q (μ sec)	I_{GT} (mA)	
T9G0	02 through 24	10	0	3	DH
	200V through 2400V	1000A	250 μ sec (Typical)	200mA	12"

Applications:

- ☐ Power Supplies
- ☐ Motor Control
- ☐ Battery Chargers

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T9G0 1000A
Phase Control SCR
 1000 Amperes Average, 2400 Volts

Absolute Maximum Ratings

Characteristics	Symbol	T9G0 1000A	Units
Non-repetitive Transient Peak Reverse Voltage	V_{RSM}	$V_{RRM} + 100V$	Volts
RMS On-state Current, $T_C = 82^\circ C$	$I_{T(rms)}$	1590	Amperes
Average Current 180° Sine Wave, $T_C = 82^\circ C$	$I_{T(av)}$	1000	Amperes
RMS On-state Current, $T_C = 55^\circ C$	$I_{T(rms)}$	2100	Amperes
Average Current 180° Sine Wave, $T_C = 55^\circ C$	$I_{T(av)}$	1340	Amperes
Peak One Cycle Surge On-state Current (Non-repetitive) 60Hz	I_{tsm}	17000	Amperes
Peak One Cycle Surge On-state Current (Non-repetitive) 50Hz	I_{tsm}	15500	Amperes
Critical Rate-of-rise of On-state Current (Non-repetitive)	di/dt	600	A/ μ sec
Critical Rate-of-rise of On-state Current (Repetitive)	di/dt	150	A/ μ sec
I^2t (for Fusing) for One Cycle, 60Hz	I^2t	1,203,000	A ² sec
Peak Gate Power Dissipation	P_{GM}	16	Watts
Average Gate Power Dissipation	$P_{G(av)}$	3	Watts
Operating Temperature	T_j	-40 to +125°C	°C
Storage Temperature	T_{stg}	-40 to +150°C	°C
Approximate Weight		1	lb.
		454	g
Mounting Force		5000 to 5500	lb.
		2270 to 2500	kg

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T9G0 1000A

Phase Control SCR

1000 Amperes Average, 2400 Volts

Electrical Characteristics, $T_j = 25^\circ\text{C}$ Unless Otherwise Specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Repetitive Peak Reverse Leakage Current	I_{RRM}	$T_j = 125^\circ\text{C}$, $V_R = V_{RRM}$			75	mA
Repetitive Peak Forward Leakage Current	I_{DRM}	$T_j = 125^\circ\text{C}$, $V_D = V_{DRM}$			75	mA
Peak On-state Voltage	V_{TM}	$I_{TM} = 1500\text{A Peak}$ Duty Cycle $< 0.1\%$			1.75	Volts
Threshold Voltage, Low-level	$V_{(TO)1}$	$T_j = 125^\circ\text{C}$, $I = 15\%$, $I_{T(av)}$ to $\pi I_{T(av)}$			0.90398	Volts
Slope Resistance, Low-level	r_{T1}				0.49075	$\text{m}\Omega$
Threshold Voltage, High-level	$V_{(TO)2}$	$T_j = 125^\circ\text{C}$, $I = \pi I_{T(av)}$ to I_{TSM}			0.96507	Volts
Slope Resistance, High-level	r_{T2}				0.42052	$\text{m}\Omega$
V_{TM} Coefficients, Low-level		$T_j = 125^\circ\text{C}$, $I = 15\%$ $I_{T(av)}$ to $\pi I_{T(av)}$			$A_1 = 0.11284$ $B_1 = 0.08444$ $C_1 = 1.569\text{E-}04$ $D_1 = 0.020707$	
V_{TM} Coefficients, High-level		$T_j = 125^\circ\text{C}$, $I = \pi I_{T(av)}$ to I_{TSM}			$A_2 = 26.048$ $B_2 = -3.9592$ $C_2 = 1.118\text{E-}04$ $D_2 = 0.14391$	
Typical Turn-on Time	t_{on}	$I_{TM} = 1000\text{A}$, $V_D = 450\text{V}$		3		μsec
Typical Turn-off Time	t_q	$T_j = 125^\circ\text{C}$, $I_T = 250\text{A}$, $di_R/dt = 50\text{A}/\mu\text{sec}$ Reapplied $dv/dt = 20\text{V}/\mu\text{sec}$ Linear to 80% V_{DRM}		250		μsec
Minimum Critical dv/dt - Exponential to V_{DRM}	dv/dt	$T_j = 125^\circ\text{C}$	300	1000		$\text{V}/\mu\text{sec}$
Gate Trigger Current	I_{GT}	$T_j = 25^\circ\text{C}$, $V_D = 12\text{V}$	30	100	200	mA
Gate Trigger Voltage	V_{GT}	$T_j = 25^\circ\text{C}$, $V_D = 12\text{V}$		1.5	3.0	Volts
Non-triggering Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}$, $V_D = V_{DRM}$			0.15	Volts
Peak Forward Gate Current	I_{GTM}				4	A
Peak Reverse Gate Voltage	V_{GRM}				5	Volts

Thermal Characteristics

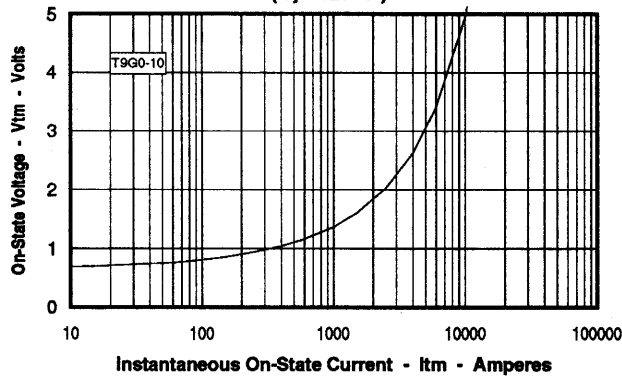
Maximum Thermal Resistance, Double Sided Cooling

Junction-to-Case	$R_{\theta(j-c)}$		0.023	$^\circ\text{C}/\text{W}$
Case-to-Sink	$R_{\theta(c-s)}$	0.006	0.0075	$^\circ\text{C}/\text{W}$

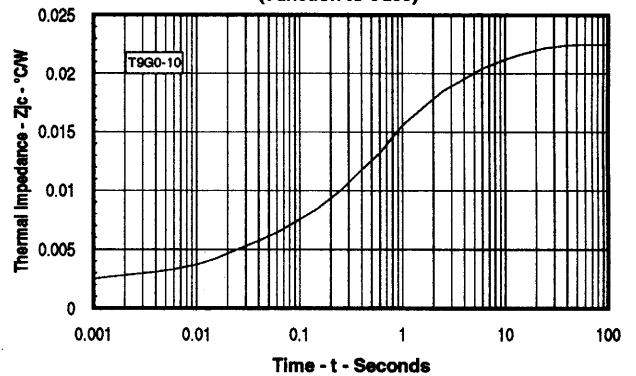
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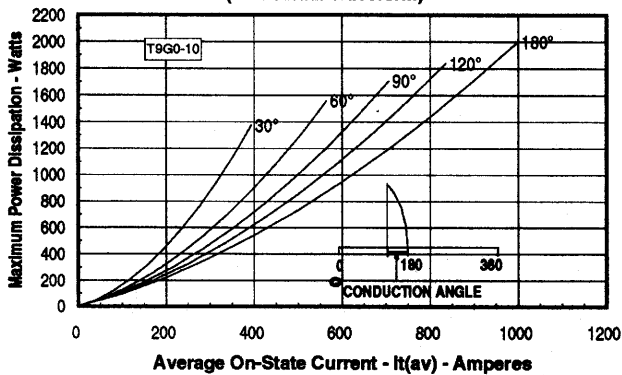
Maximum On-State Forward Voltage Drop
($T_J = 125^\circ\text{C}$)



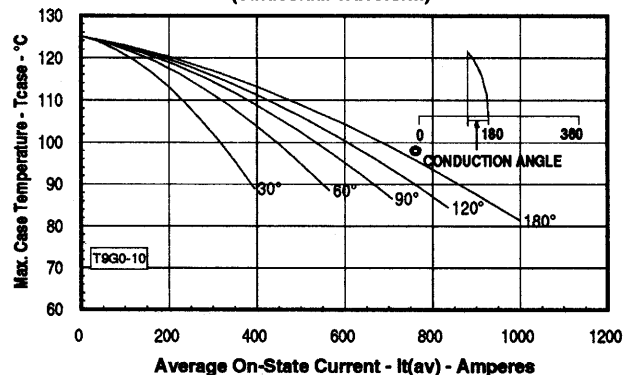
Maximum Transient Thermal Impedance
(Junction to Case)



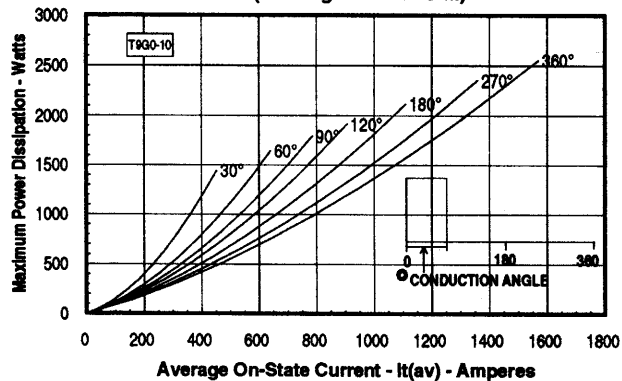
Maximum On-State Power Dissipation
(Sinusoidal Waveform)



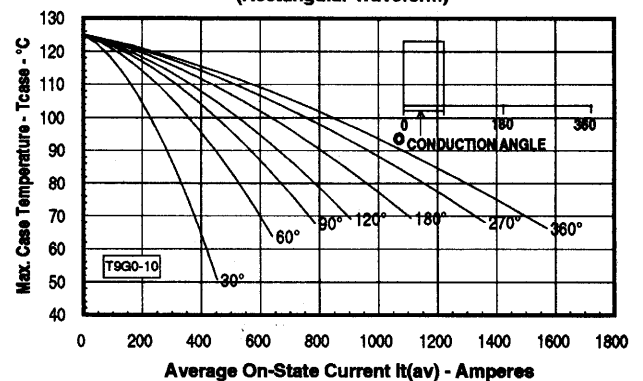
Maximum Allowable Case Temperature
(Sinusoidal Waveform)



Maximum On-State Power Dissipation
(Rectangular Waveform)



Maximum Allowable Case Temperature
(Rectangular Waveform)



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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